

1.3MP SWIR Camera inside Semiconductor Internal Observation Microscope

Model.NIR2021-200

Is a microscope for observing the inside of semiconductor devices such as silicon wafers, chips, MEMS, and CSPs using the transmission / reflection



makes it possible to observe the inside of mounted IC chips that do not pass through the visible light.



Feature

- Built-in SWIR camera equipped with a 1.3MP SONY IMX990 with a pixel size of 5µm enables acquisition of high-resolution near-infrared images.
- The imaging lens barrel and PEIR objective lens series specially designed for the near-infrared region of 1100-1700 nm, which has high sensitivity of SWIR cameras, acquire high-contrast images even on thick wafers and high-density wafers.
- A high-power near-infrared halogen light source is standard equipment, and a sufficiently bright image can be obtained even when using an 100x objective lens.
- Equipped with an 8-inch wafer mounting stage. There are options such as vibration isolation table, wafer loader, etc.

SEIWA OPTICAL CO., LTD.



System configuration



Near IR lens for Photo emission application

MODEL#	М	N.A	WD(mm)	FOV(H×Vmm)
PEIRPlan1X	1x	0.03	12	6.4X5.12
PEIRPlan2.5X	2.5x	0.1	28	2.56X2.048
PEIRPlan10X	10x	0.27	30.4	0.64X0.512
PEIRPlan20X	20x	0.5	12	0.32X0.256
PEIRPlan50X	50x	0.6	10	0.128X0.1024
PEIRPlan100X	100x	0.71	9.5	0.064X0.0512

Near IR 2000nm Objective Lens

MODEL#	М	N.A	WD(mm)	FOV(H×Vmm)
PEIRPlan20X2000HR	20x	0.6	10	0.32X0.256
PEIRPlan50X2000HR	50x	0.7	10	0.128X0.1024



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In case of magnification with 20X or more, Correction caps can be supported as option to correct aberrations caused by silicon layers.



Specification of standard configuration

Main body

Imaging optical unit	f =200mm Bulit in imaging lenses coated with NIR		
Revolver	4 position with f	4 position with function of adjusting center	
Coaxial light port	With adjustment knob of apurture		
Foucas	Stroke	±25mm	
	Flutter	4mm / per rotation of knob	
	Fine	0.1mm / per rotation of knob	
Stage	Stroke	205 x 205mm	
	Transmitted illumination range	150 x 150mm	

1.3MP InGaAs camera

Output pixels	1280 x 1024
Cell size	5um x 5um
Area size	6.4 x 5.12mm
Flame rate	70fps(12bit)
Interface	USB3

NIR halogen light

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Model	SIS-150-AIR
Rated voltage	AC100-240V
Rated input frequency	50/60 Hz
Lighting methods	DC lighting
Adjustment of light	Variable output voltage
intensity	Variable range of voltageDC2V-15V
	Variable range of light volume: $0.1\%\sim100\%$
Protection	Overcurrent circuit(Power shutdown and recovery)
	Overheat circuit(Auto recovery)
Cooling methods	Forced fan cooling
Operation temp /	0℃-40℃/20%-80%rh
Humidity	(No condensation)
Functions	Lamp burnout signal output
	: Open collector, Emitter
	Analog signal voltage control
	:DC0-5V input
	Turn lamp On/Off remotely by
	inputting DC5V
Dimonsions	W124 x H165 x D224mm
Diffensions	(Excluding protrusions)
Wevelength range	400-1700nm
Light guide	Heat resistant type 2M
Bandpass filter	With a detachable plate 1100um

Software functions

Camera control		Control an exposure time
Screen	LUT	Contrast enhancement
display	Zoom	Resize the live & still image
	Scale	Display a digital scale on screen
	Inversion of	Invert the mirror vertically and
	mirror	horizontally
	Tool of	
	displaying cross	Display a cross line on screen
	line	
Image	Measurement	Distance between two specified
processing	of distance	points.
&	Contrast	Histogram correction
Measurement	enhancement	
	Profile	Display a graph of brightness
	rionie	values on specified line
Save image	Image format	TIFF, BMP, JPEG, AVI
Camera control		Windows7 or later

Recommended PC specification

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Intel ICH series (6 or later)		
CPU	Intel Core I7 6700	
Available memory	1024MB or more	





Optional product

Transmitted illumination unit



Bandpass filter



Vibration isolator with air spring



Wafer loader



Transmitted illumination unit

NIR light source	SIS-150-AIR
Light guide	Heat resistant type
Lens for	
transmitted	Built in right angle lens for NIR
illumination	

Band pass filter

1200nm	SIS-BPF-1200
1300nm	SIS-BPF-1300
1400nm	SIS-BPF-1400
1500nm	SIS-BPF-1500

Long pass filter

All over 1100nm SIS-LPF-1100

Vibration isolator with air spring

Model No	SPB-5AA-5060-SPCC
Natural	About 2.5Hz
frequency(Hz)	
Attenuation effect	Diaphragm type air spring
Levelling method	Auto levelling with air supply
	(0.4-0.7MPa)
Surface plate	SUS304
Dimension	W500xD600xH61mm
Weight	27Кд
Loadable weight	Up to 120kg
Accesorries	Urethane tube φ6x3 m, RT 1/8 male
	coupler

Wafer loader

Supported wafer size	6 inch or 8 inch	
Cassette	SEMI standard 25 pcs set	
Number of cassette	1	
Transport	Surface macro inspection	
sequence	Backside macro inspection	
	Backside macro re-inspection	
Oriental flat / Notch position	Non-contact setting method	
Dimension	W 620mm x D 550mm x H 308mm	
Weight	47Kg	
Utility	Power :AC100-240V 2A-1A 50/60Hz Vacuum :-80kpa Connection diameter:6mm	

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